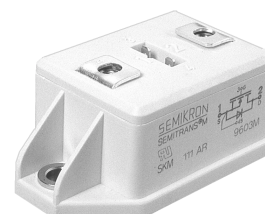


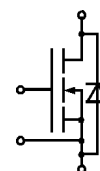
SEMITRANS® M Power MOSFET Modules

SKM 151 A4R

Preliminary Data



SEMITRANS M1



Features

- N Channel, enhancement mode
- Short internal connections avoid oscillations
- With built-in gate resistor chips ("R") $R_{gtotal} = 1,3 \Omega$
- Without hard mould (environmental aspects)
- Isolated copper baseplate using DCB Direct Copper Bonding Ceramic
- All electrical connections on top for easy busbaring
- Large clearance (10 mm) and creepage distances (13 mm)
- UL recognized, file no. E63 532

Typical Applications

- Switched mode power supplies
- DC servo and robot drives
- DC choppers
- Resonant and welding inverters
- AC motor drives
- Laser power supplies
- UPS equipment
- Not suitable for linear amplification

This is an electrostatic discharge sensitive device (ESDS). Please observe the international standard IEC 747-1, Chapter IX.

Absolute Maximum Ratings		Values	Units
Symbol	Conditions ¹⁾		
V_{DS}		500	V
V_{DGR}	$R_{GE} = 20 \text{ k}\Omega$	500	V
I_D	$T_c = 25 / 80 \text{ }^\circ\text{C}$	70 / 50	A
I_{DM}	$T_c = 25 / 80 \text{ }^\circ\text{C}$	280 / 200	A
V_{GS}		± 20	V
P_D		780	W
$T_j, (T_{stg})$		-40 ... +150 (125)	$^\circ\text{C}$
V_{isol}	AC, 1 min.	2 500	V
humidity	DIN 40 040	Class F	
climate	DIN IEC 68 T.1	40/125/56	
Inverse Diode			
$I_F = -I_D$	$T_c = 25 / 80 \text{ }^\circ\text{C}$	70 / 50	A
$I_{FM} = -I_{DM}$	$T_c = 25 / 80 \text{ }^\circ\text{C}$	280 / 200	A

Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
$V_{(BR)DSS}$	$V_{GS} = 0, I_D = 0,25 \text{ mA}$	500	—	—	V
$V_{GS(th)}$	$V_{GS} = V_{DS}, I_D = 1 \text{ mA}$	2,1	3,0	4,0	V
I_{DSS}	$V_{GS} = 0$	—	1	250	μA
	$V_{DS} = 500 \text{ V}$	—	300	1000	μA
I_{GSS}	$V_{GS} = 20 \text{ V}, V_{DS} = 0$	—	10	100	nA
$R_{DS(on)}$	$V_{GS} = 10 \text{ V}, I_D = 50 \text{ A}$	—	50	70	m Ω
g_{fs}	$V_{DS} = 25 \text{ V}, I_D = 50 \text{ A}$	48	90	—	S
C_{CHC}		—	—	160	pF
C_{iss}	$V_{GS} = 0$	—	15	20	nF
C_{oss}	$V_{DS} = 25 \text{ V}$	—	1,9	2,9	nF
C_{rss}	$f = 1 \text{ MHz}$	—	0,72	1,1	nF
L_{DS}		—	—	30	nH
$t_{d(on)}$	$V_{DD} = 250 \text{ V}$	—	60	—	ns
t_r	$I_D = 30 \text{ A}$	—	100	—	ns
$t_{d(off)}$	$V_{GS} = 10 \text{ V}$	—	500	—	ns
t_f	$R_G = 4,7 \Omega$	—	120	—	ns
Inverse Diode					
V_{SD}	$I_F = 120 \text{ A}, V_{GS} = 0 \text{ V}$	—	1,0	1,4	V
t_{rr}	$T_j = 25 \text{ }^\circ\text{C} \text{ }^2)$	—	450	—	ns
	$T_j = 150 \text{ }^\circ\text{C} \text{ }^2)$	—	—	—	ns
Q_{rr}	$T_j = 25 \text{ }^\circ\text{C} \text{ }^2)$	—	36	—	μC
	$T_j = 150 \text{ }^\circ\text{C} \text{ }^2)$	—	—	—	
Thermal characteristics					
R_{thjc}		—	—	0,16	$^\circ\text{C/W}$
R_{thch}	M_1 , surface $10 \mu\text{m}$	—	—	0,05	$^\circ\text{C/W}$

Mechanical Data					
M_1	to heatsink, SI Units	4	—	6	Nm
	to heatsink, US Units	35	—	53	lb.in.
M_2	for terminals, SI Units	2,5	—	3,5	Nm
	for terminals, US Units	22	—	24	lb.in.
a		—	—	5x9,81	m/s ²
w		—	—	150	g
Case	page 5	D15			

¹⁾ $T_{case} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

²⁾ $I_F = -I_D, V_R = 100 \text{ V}, -di_F/dt = 100 \text{ A}/\mu\text{s}$

Do not parallel with former SKM 151 or SKM 151F (which are discontinued)

SKM 151 A4R can replace SKM 151, former SKM 151 R and SKM 151 AR

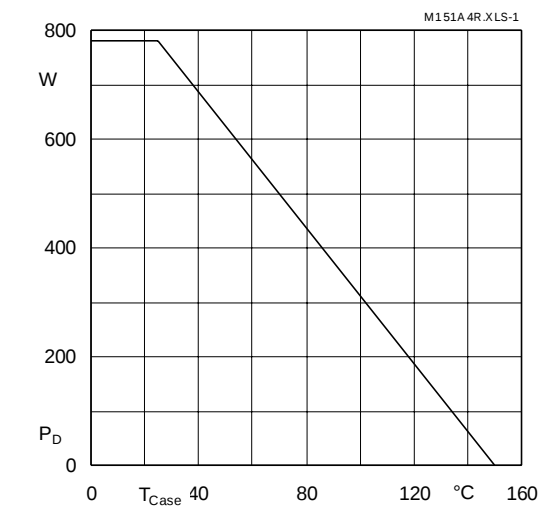


Fig. 1 Rated power dissipation vs. temperature

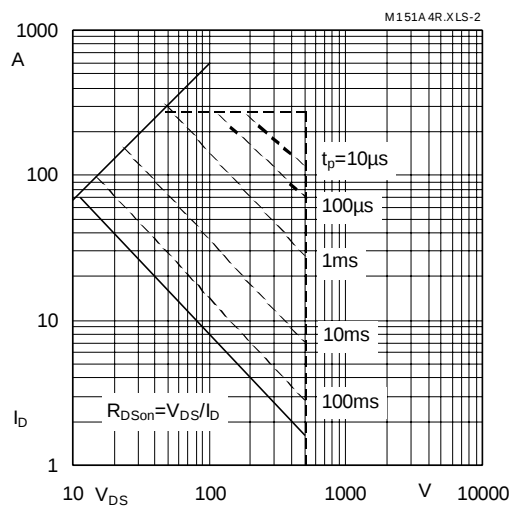


Fig. 2 Maximum safe operating area

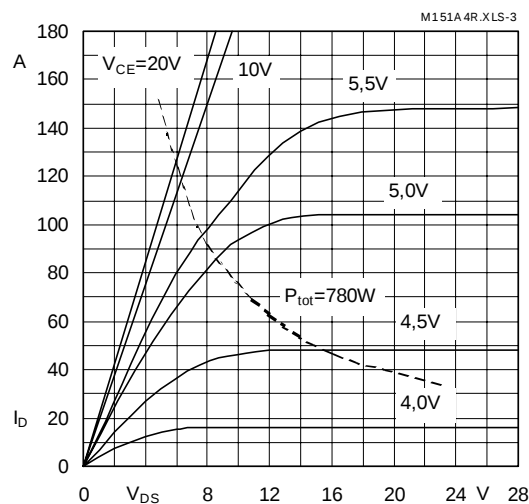


Fig. 3 Output characteristic

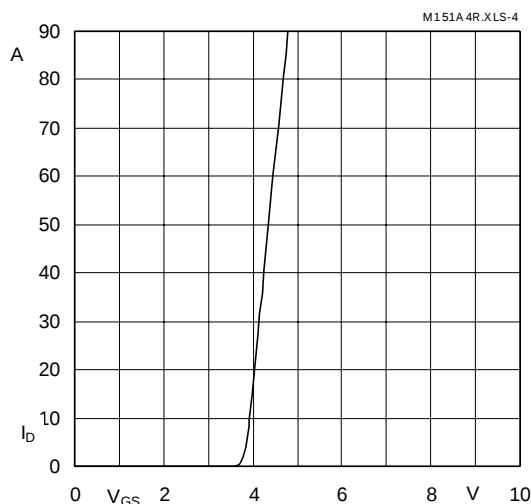


Fig. 4 Transfer characteristic

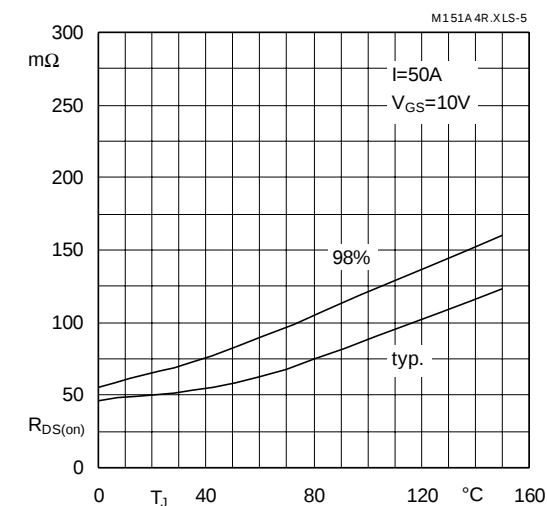


Fig. 5 On-resistance vs. temperature

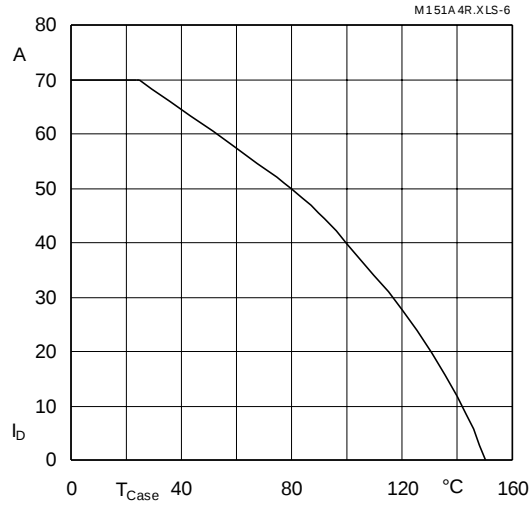


Fig. 6 Rated current vs. temperature

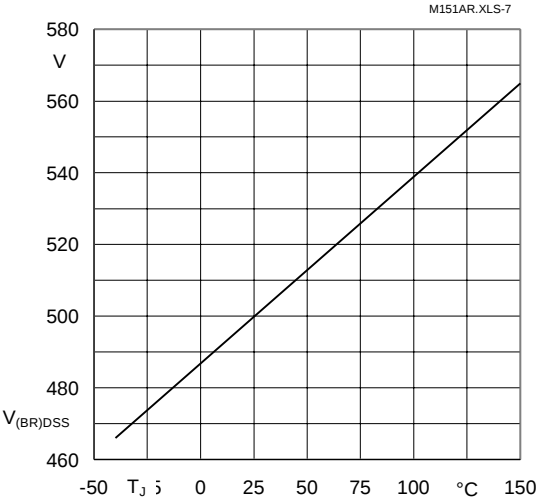


Fig. 7 Breakdown voltage vs. temperature

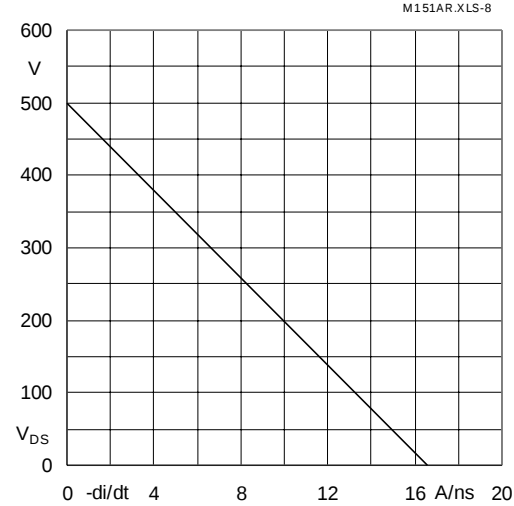


Fig. 8 Drain-source voltage derating

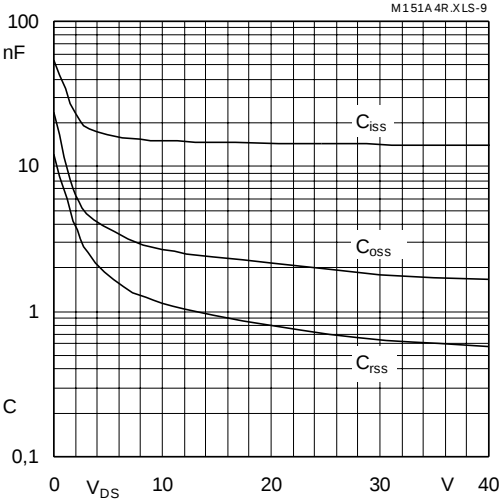


Fig. 9 Capacitances vs. drain-source voltage

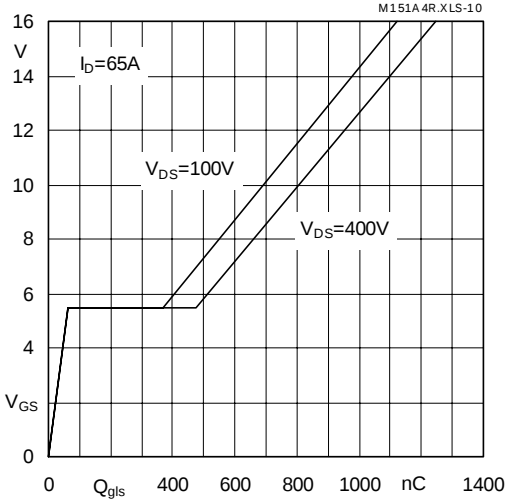


Fig. 10 Gate charge characteristic

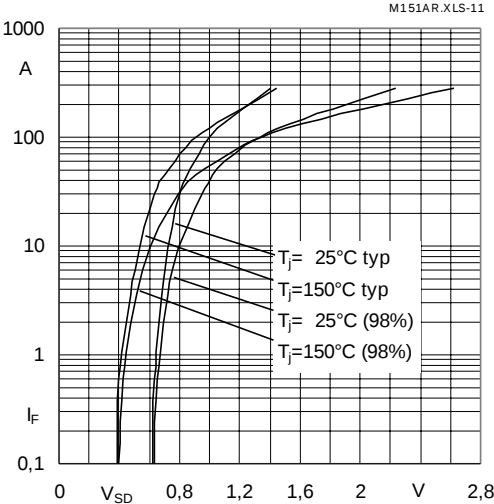


Fig. 11 Diode forward characteristic

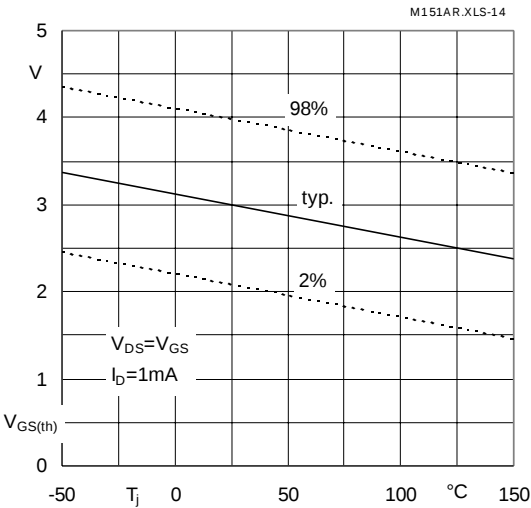


Fig. 14 Gate-source threshold voltage

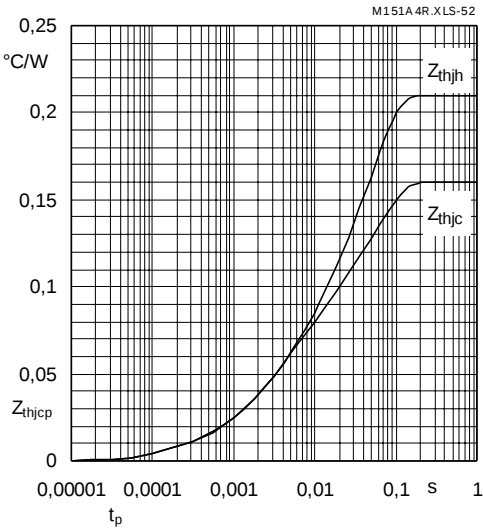


Fig. 51 Transient thermal impedance

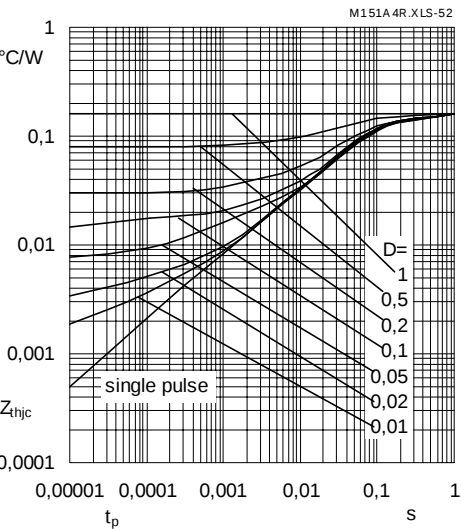


Fig. 52 Thermal impedance under pulse conditions

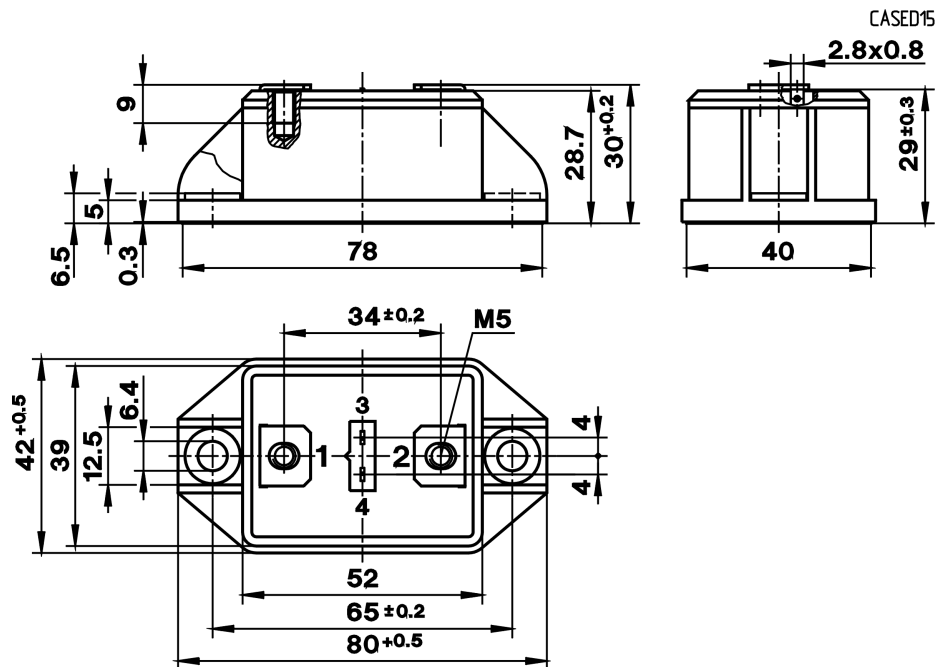
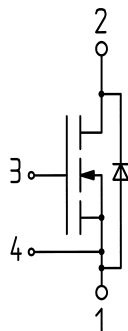
SKM 151 A4R

SEMITRANS M 1

Case D 15

UL recognized, file No. E63 5632

SKM 151 A4R



Outline and circuit diagram